# onsemi

## Octal D-Type Flip-Flop with 3-STATE Outputs

## 74VHCT574A



The VHCT574A is an advanced high speed CMOS octal flip-flop with 3–STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8–bit D–type flip– flop is control led by a clock input (CP) and an Output Enable input ( $\overline{OE}$ ). When the  $\overline{OE}$  input is HIGH, the eight outputs are in a high impedance state.

Protection circuits ensure that 0 V to 5.5 V can be applied to the input and output (Note 1) pins without regard to the supply voltage. This device can be used to interface 3 V to 5 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

NOTE:

1. Outputs in OFF-State.

#### Features

- High Speed:  $f_{MAX} = 140$  MHz (Typ) at  $T_A = 25^{\circ}C$
- Power Down Protection is Provided on All Inputs and Outputs
- Low Noise:  $V_{OLP} = 1.6 V (Max)$
- Low Power Dissipation:  $I_{CC} = 4 \mu A (Max) @ T_A = 25^{\circ}C$
- Pin and Function Compatible with 74HCT574
- This is a Pb–Free Device

#### Logic Symbol

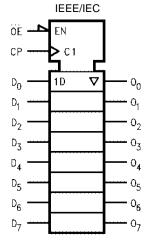
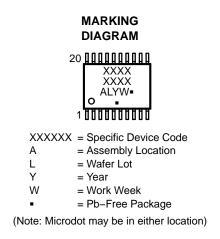
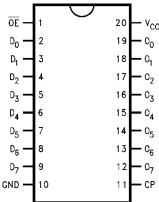


Figure 1. Logic Symbol



TSSOP20, 4.4x6.5 CASE 948AQ





### CONNECTION DIAGRAM

#### **PIN DESCRIPTIONS**

Pin Names	Description
D <sub>0</sub> –D <sub>7</sub>	Data Inputs
CP	Clock Pulse Input 3–STATE
ŌE	Output Enable Input 3–STATE
O <sub>0</sub> –O <sub>7</sub>	Outputs

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### TRUTH TABLE

	Outputs		
D <sub>n</sub>	СР	ŌĒ	O <sub>n</sub>
н	~	L	н
L	~	L	L
х	х	н	Z

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

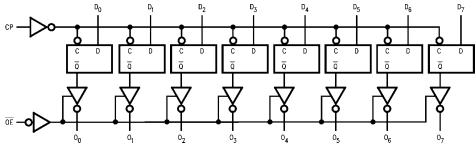
Z = High Impedance

✓ = LOW-to-HIGH Transition

#### Logic Diagram

#### **Functional Description**

The VHCT574A consists of eight edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The buffered clock and buffered Output Enable are common to all flip-flops. The eight flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP) transition. With the Output Enable ( $\overline{OE}$ ) LOW, the contents of the eight flip-flops are available at the outputs. When the  $\overline{OE}$  is HIGH, the outputs go to the high impedance state. Operation of the  $\overline{OE}$  input does not affect the state of the flip-flops.



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

#### Figure 2. Logic Diagram

#### MAXIMUM RATINGS

Symbol	P	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +6.5	V	
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	DC Output Voltage	Active Mode (High or Low State)	–0.5 to V <sub>CC</sub> + 0.5	V
		Tristate Mode (Note 2)	-0.5 to +6.5	
		Power–Off Mode ( $V_{CC} = 0 V$ )	-0.5 to +6.5	1
I <sub>IN</sub>	DC Input Current, per Pin	±20	mA	
I <sub>OUT</sub>	DC Output Current, per Pin	±25	mA	
I <sub>CC</sub>	DC Supply Current, $V_{CC}$ and GND Pir	±75	mA	
I <sub>IK</sub>	Input Clamp Current		-20	mA
I <sub>OK</sub>	Output Clamp Current		-20	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case f	or 10 Seconds	260	°C
ТJ	Junction Temperature under Bias		+150	°C
$\theta_{JA}$	Thermal Resistance (Note 3)		150	°C/W
PD	Power Dissipation in Still Air at 25°C		833	mW
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.574 in	
V <sub>ESD</sub>	ESD Withstand Voltage (Note 4)	Human Body Model	2000	V
		Charged Device Model	N/A	1

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2. Applicable to devices with outputs that may be tri-stated.

3. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.

 HBM tested to EIA / JESD22–A114–A. CDM tested to JESD22–C101–A. JEDEC recommends that ESD qualification to EIA/JESD22–A115A (Machine Model) be discontinued.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol		Min	Max	Unit	
V <sub>CC</sub>	DC Supply Voltage			5.5	V
V <sub>IN</sub>	DC Input Voltage (Note 5)	0	5.5	V	
V <sub>OUT</sub>	DC Output Voltage (Note 5)	Active Mode (High or Low State)	0	V <sub>CC</sub>	V
		Tristate Mode	0	5.5	
		Power–Off Mode ( $V_{CC} = 0 V$ )	0	5.5	
T <sub>A</sub>	Operating Temperature	•	-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Rate	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
5. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

#### DC ELECTRICAL CHARACTERISTICS

					T <sub>A</sub> = 25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Parameter	Cor	ditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level			4.5	2.0	-	-	2.0	-	V
	Input Voltage			5.5	2.0	-	-	20	-	
VIL	LOW Level			4.5	-	-	0.8	-	0.8	V
	Input Voltage			5.5	-	-	0.8	-	0.8	
V <sub>OH</sub>	HIGH Level	$V_{IN} = V_{IH}$	I <sub>OH</sub> = -50 μA	4.5	4.40	4.50	-	4.40	-	V
	Output Voltage or V <sub>IL</sub>	or v <sub>IL</sub>	I <sub>OH</sub> = -8 mA		3.94	-	-	3.80	-	V
V <sub>OL</sub>	LOW Level	$V_{IN} = V_{IH}$	I <sub>OL</sub> = 50 μA	4.5	-	0.0	0.1	-	0.1	V
Output Voltage	Output voltage	or V <sub>IL</sub>	I <sub>OL</sub> = 8 mA		-	-	0.36	-	0.44	V
I <sub>OZ</sub>	3–STATE Output Off–State Current	$V_{IN} = V_{IH} c$ $V_{OUT} = V_C$		5.5	-	-	±0.25	-	±2.5	μΑ
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V	' or GND	0–5.5	-	-	±0.1	-	±1.0	μΑ
Icc	Quiescent Supply Current	$V_{IN} = V_{CC}$	or GND	5.5	-	-	4.0	-	40.0	μΑ
ICCT	Maximum I <sub>CC</sub> /Input	$V_{IN} = 3.4 \text{ V}$ Other Input = $V_{CC}$ or GND		5.5	-	-	1.35	-	1.50	mA
I <sub>OFF</sub>	Output Leakage Current (Power Down State)	V <sub>OUT</sub> = 5.5	V	0.0	-	-	0.5	-	5.0	μΑ

#### **NOISE CHARACTERISTICS**

				T <sub>A</sub> = 25°C		
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Тур	Limits	Unit
V <sub>OLP</sub> (Note 6)	Quiet Output Maximum Dynamic V <sub>OL</sub>	C <sub>L</sub> = 50 pF	5.0	1.2	1.6	V
V <sub>OLV</sub> (Note 6)	Quiet Output Minimum Dynamic V <sub>OL</sub>	C <sub>L</sub> = 50 pF	5.0	-1.2	-1.6	V
V <sub>IHD</sub> (Note 6)	Minimum HIGH Level Dynamic Input Voltage	C <sub>L</sub> = 50 pF	5.0	-	2.0	V
V <sub>ILD</sub> (Note 6)	Maximum LOW Level Dynamic Input Voltage	C <sub>L</sub> = 50 pF	5.0	-	0.8	V

6. Parameter guaranteed by design.

#### **AC ELECTRICAL CHARACTERISTICS**

				T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to +85°C			
Symbol	Parameter	Con	ditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub>	Propagation		C <sub>L</sub> = 15 pF	5.0 ±0.5	_	4.1	9.4	1.0	10.5	ns
t <sub>PHL</sub>	Delay Time		C <sub>L</sub> = 50 pF		-	5.6	10.4	1.0	11.5	
t <sub>PZL</sub>	3-STATE Output	$R_L = 1 \ k\Omega$	C <sub>L</sub> = 15 pF	5.0 ±0.5	-	6.5	10.2	1.0	11.5	ns
t <sub>PZH</sub>	Enable Time		C <sub>L</sub> = 50 pF		-	7.3	11.2	1.0	12.5	
t <sub>PLZ</sub> t <sub>PHZ</sub>	3–STATE Output Disable Time	$R_L = 1 \ k\Omega$	C <sub>L</sub> = 50 pF	5.0 ±0.5	-	7.0	11.2	1.0	12.0	ns
t <sub>OSLH</sub> t <sub>OSHL</sub>	Output to Output Skew	(Note 7)		5.0 ±0.5	-	-	1.0	-	1.0	ns
f <sub>MAX</sub>	Maximum Clock		C <sub>L</sub> = 15 pF	5.0 ±0.5	90	140	-	80	-	MHz
	Frequency		C <sub>L</sub> = 50 pF		85	130	-	75	-	
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = Oper	n		-	4	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 5.0 \	/		-	9	-	-	-	pF
C <sub>PD</sub>	Power Dissipation Capacitance	(Note 8)			-	25	_	-	-	pF

Parameter guaranteed by design. t<sub>OSLH</sub> – |t<sub>PLH</sub> max – t<sub>PLH</sub> min|; t<sub>OSHL</sub> – |t<sub>PHL</sub> max – t<sub>PHL</sub> min|
 C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC</sub> (opr.) = C<sub>PD</sub> x V<sub>CC</sub> x f<sub>IN</sub> + I<sub>CC</sub>/8 (per F/F). The total C<sub>PD</sub> when n pcs. of the Octal D Flip–Flop operates can be calculated by the equation: C<sub>PD</sub> (total) = 20 + 12n.

#### **AC OPERATING REQUIREMENTS**

			T <sub>A</sub> = 25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			
Symbol	Parameter	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
t <sub>W</sub> (H) t <sub>W</sub> (L)	Minimum Pulse Width (CP)	5.0 ±0.5	6.5	-	-	8.5	-	ns
t <sub>S</sub>	Minimum Set–Up Time	5.0 ±0.5	2.5	-	-	2.5	-	ns
t <sub>H</sub>	Minimum Hold Time	5.0 ±0.5	2.5	-	-	2.5	-	ns

#### **ORDERING INFORMATION**

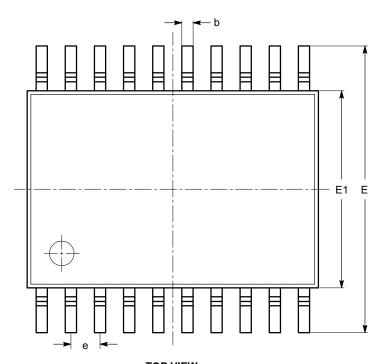
Device	Marking	Package	Shipping <sup>†</sup>
74VHCT574AMTCX	VHCT 574A	TSSOP20 (Pb–Free)	2500 Units / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



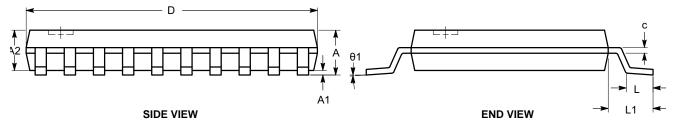
TSSOP20, 4.4x6.5 CASE 948AQ ISSUE A

DATE 19 MAR 2009



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
E	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°





#### Notes:

All dimensions are in millimeters. Angles in degrees.
 Complies with JEDEC MO-153.

DOCUMENT NUMBER:	98AON34453E	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	TSSOP20, 4.4X6.5		PAGE 1 OF 1			
the right to make changes without furth purpose, nor does <b>onsemi</b> assume ar	er notice to any products herein. <b>onsemi</b> make ny liability arising out of the application or use	LLC dba <b>onsemi</b> or its subsidiaries in the United States and/or other course no warranty, representation or guarantee regarding the suitability of its product or circuit, and specifically disclaims any and all liability, in e under its patent rights nor the rights of others.	products for any particular			

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>